

UMS-300-R16-G

OCTAVE BAND VOLTAGE CONTROLLED OSCILLATOR

Package: R16, 12.7mm x 12.7mm x 4.57mm

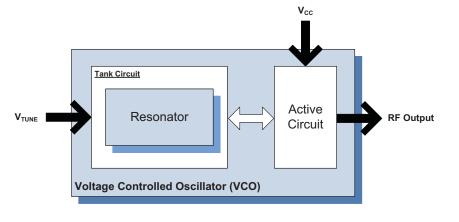


Features

- Octave Band Tuning
- Frequency: 150MHz to 300MHz
- Resonator: Microstrip
- PCB: Rogers
- Package Size: 12.7mm x 12.7mm x 4.57mm (0.5in x 0.5in x 0.18in)

Applications

- Wide Band Applications
- Built-in Test Applications
- First LO Applications
- Frequency Sythesizers



Functional Block Diagram

Product Description

This series of VCO modules features full octave bands (typical), low phase noise, low harmonics, and linear tuning.

Ordering Information

UMS-300-R16-G Contact us at 1-480-756-6070

Optimum Technology Matching® Applied

GaAs HBT
GaAs MESFET
InGaP HBT

support, contact

SiGe BiCMOS
Si BiCMOS
SiGe HBT

332-678-5570 or customerspryice@rfmd.

□ GaAs pHEMT □ GaN HEMT □ Si CMOS □ BiFET HBT ☑ Si BJT □ LDMOS

m.

RF MICRO DEVICES®, RFMD®, Optimum Technology Matching®, Enabling Wireless Connectivity^{IM}, PowerStar®, POLARIS^{IM} TOTAL RADIO^{IM} and UltimateBlue^{IM} are trademarks of RFMD, LLC. BLUETOOTH is a trade mark owned by Bluetooth SIG, Inc., U.S.A. and licensed for use by RFMD. All other trade names, trademarks and registered trademarks are the property of their respective owners. ©2006, RF Micro Devices, Inc. 7628 Thorndike Road, Greensboro, NC 27409-9421 · For sales or technical

UMS-300-R16-G



Absolute Maximum Ratings

•		
Parameter	Rating	Unit
Operating Ambient Temperature[1]	-40 to +85	°C
Storage Temperature	-55 to +125	°C

[1] Frequency drift: 2.0MHz typical, 4.0MHz maximum at -40 °C and 2.0MHz typical, 3.0MHz maximum at +85 °C.



Caution! ESD sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

The information in this publication is believed to be accurate and reliable. However, no responsibility is assumed by RF Micro Devices, Inc. ("RFMD") for its use, nor for any infringement of patents, or other rights of third parties, resulting from its use. No license is granted by implication or otherwise under any patent or patent rights of RFMD. RFMD reserves the right to change component circuitry, recommended application circuitry and specifications at any time without prior notice.



RoHS (Restriction of Hazardous Substances): Compliant per EU Directive 2002/95/EC.

Parameter	Specification		11		
	Min.	Тур.	Max.	Unit	Condition
Overall					
Frequency Range	150		300	MHz	
Tuning Voltage	1		16	V _{DC}	
Tuning Sensitivity		12		MHz/V	
Output Power	7	10	12	dBm	
	5				At V _T = 0
Output Phase Noise		-78	-73	dBc/Hz	1kHz
		-103	-96	dBc/Hz	10kHz
		-123	-116	dBc/Hz	100 kHz
		-143	-136	dBc/Hz	1000kHz
		-155	-150	dBc/Hz	10000kHz
Second Harmonic		-28	-20	dBc	
Frequency Pulling		1	3	MHz p-p	At 12dBr, all phases
Tuning Port Capacitance		330		pF	
Modulation Bandwidth		100		kHz	3dB BW
Frequency Pushing		0.2	0.5	MHz/V	
Power Supply	· · ·		·		
Operating Voltage		12		V	
Supply Current		16		mA	





Package Drawing & Pin Outs

12.7mm x 12.7mm x 4.57mm (0.5in x 0.5in x 0.18in)

